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Correction: Helium-induced damage in U_3Si_5 by first-principles studies

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Correction for 'Helium-induced damage in U_3Si_5 by first-principles studies' by Yibo Wang *et al.*, *RSC Adv.*, 2021, **11**, 26920–26927. DOI: 10.1039/D1RA04031F.

The authors regret that an incorrect version of Fig. 4 was included in the original article. The correct version of Fig. 4 is presented below.

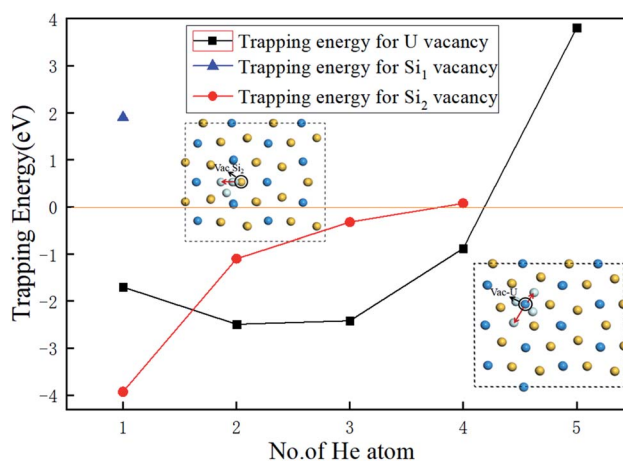


Fig. 4 The dependence of the trapping energy on the number of He atoms trapped in Vac-U, Vac-Si₁, and Vac-Si₂ vacancies of U_3Si_5 .

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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